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- 150-mA Low Noise, Low-Dropout Regulator
- Output Voltage: 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V
- Output Noise Typically 50 μV
- Quiescent Current Typically 85 μA
- Dropout Voltage, Typically 300 mV at 150 mA
- Thermal Protection
- Over Current Limitation
- Less Than 2-μA Quiescent Current in Shutdown Mode
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 (DBV) Package

description

The TPS764xx family of low-dropout (LDO) voltage regulators offers the benefits of a low noise, low-dropout voltage, low-power operation, and miniaturized package. Additionally, they feature low quiescent current when compared to conventional LDO regulators. Offered in 5-terminal small outline integrated-circuit SOT-23 package, the TPS764xx series devices are ideal for low-noise applications, cost-sensitive designs and applications where board space is at a premium.

A combination of new circuit design and process innovation has enabled the usual pnp pass transistor to be replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is very low—typically 300 mV at 150 mA of load current (TPS76433)—and is directly proportional to the load current. Since the PMOS pass element is a voltage-driven device, the quiescent current is very low (140 μ A maximum) and is stable over the entire range of output load current (0 mA to 150 mA). Intended for use in portable systems such as laptops and cellular phones, the low-dropout voltage feature and low-power operation result in a significant increase in system battery operating life.

The TPS764xx also features a logic-enabled sleep mode to shut down the regulator, reducing quiescent current to 1 μ A maximum at T_J = 25°C.The TPS764xx is offered in 2.5-V, 2.7-V, 2.8-V, 3.0-V, and 3.3-V fixed-voltages.

Тj	VOLTAGE	PACKAGE	PART N	SYMBOL	
-40°C to 125°C	2.5 V	SOT-23 (DBV)	TPS76425DBVT [†]	TPS76425DBVR [‡]	PBJI
	2.7 V		TPS76427DBVT [†]	TPS76427DBVR [‡]	PBKI
	2.8 V		TPS76428DBVT [†]	TPS76428DBVR [‡]	PCEI
	3.0 V		TPS76430DBVT [†]	TPS76430DBVR [‡]	PBLI
	3.3 V		TPS76433DBVT [†]	TPS76433DBVR [‡]	PBMI

AVAILABLE OPTIONS

[†] The DBVT passive indicates tape and reel of 250 parts.

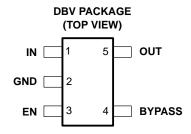
[‡] The DBVR passive indicates tape and reel of 3000 parts.



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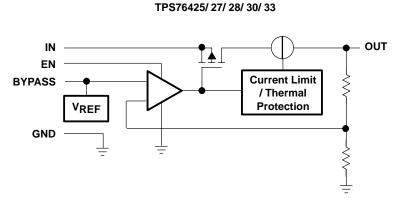
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functional block diagram



Terminal Functions

TERMINAL	1/0	DESCRIPTION					
NAME	"0	DESCRIPTION					
GND		Ground					
EN	Ι	Enable input					
BYPASS		Output bypass capacitor					
IN	Ι	Input supply voltage					
OUT	0	Regulated output voltage					

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Input voltage range (see Note 1)	
Voltage range at EN	
Voltage on OUT,	
Peak output current	Internally limited
ESD rating, HBM	
Continuous total power dissipation	See dissipation rating tables
Operating virtual junction temperature range, T _J	–40°C to 150°C
Storage temperature range, T _{stg}	–65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

BOARD	PACKAGE	$R_{\theta JC}$	$R_{\theta JA}$	DERATING FACTOR ABOVE T _A = 25°C	T _A ≤ 25°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
Low K‡	DBV	65.8 °C/W	259 °C/W	3.9 mW/°C	386 mW	212 mW	154 mW
High K§	DBV	65.8 °C/W	180 °C/W	5.6 mW/°C	555 mW	305 mW	222 mW

[‡] The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board.
§ The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.



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recommended operating conditions

	MIN	NOM M	٩X	UNIT
Input voltage, VI [†]	2.7		10	V
Continuous output current, IO	0	1	50	mA
Operating junction temperature, TJ	-40	1	25	°C

⁺ To calculate the minimum input voltage for your maximum output current, use the following equation: V_{I(min)} = V_{O(max)} + V_{DO(max load)}

electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(typ)} + 1 V$, $I_O = 1 mA$, EN = IN, $C_o = 4.7 \mu F$ (unless otherwise noted)

PARAMETER			TEST CON	NDITIONS	MIN	TYP	MAX	UNIT
			I _O = 1 mA to 100 mA,	TJ = 25°C	2.45	2.5	2.55	
		TPS76425	I _O = 1 mA to 100 mA	7	2.425	2.5	2.575	V
		1P3/0425	I _O = 1 mA to 150 mA,	T _J = 25°C	2.438	2.5	2.562	v
			I _O = 1 mA to 150 mA		2.407	2.5	2.593	
			I _O = 1 mA to 100 mA,	TJ = 25°C	2.646	2.7	2.754	
		TD070407	I _O = 1 mA to 100 mA		2.619	2.7	2.781	
		TPS76427	I _O = 1 mA to 150 mA,	TJ = 25°C	2.632	2.7	2.768	V
			I _O = 1 mA to 150 mA		2.598	2.7	2.8013	
			I _O = 1 mA to 100 mA	T _J = 25°C	2.744	2.8	2.856	V
Vo	Output voltage	TD070400	I _O = 1 mA to 150 mA,		2.73	2.8	2.870	
٧٥		TPS76428	I _O = 1 mA to 150 mA,	TJ = 25°C	2.716	2.8	2.884	
			I _O = 1 mA to 150 mA		2.695	2.8	2.905	
		TPS76430	I _O = 1 mA to 100 mA,	TJ = 25°C	2.94	3.0	3.06	V
			I _O = 1 mA to 100 mA		2.925	3.0	3.075	
			I _O = 1 mA to 150 mA,	TJ = 25°C	2.91	3.0	3.090	
			I _O = 1 mA to 150 mA		2.887	3.0	3.112	
		TPS76433	I _O = 1 mA to 100 mA,	T _J = 25°C	3.234	3.3	3.366	M
			I _O = 1 mA to 100 mA		3.201	3.3	3.399	
			$I_{O} = 1 \text{ mA to } 150 \text{ mA},$	T _J = 25°C	3.218	3.3	3.382	V
			I _O = 1 mA to 150 mA		3.177	3.3	3.423	
l(Q)	Quiescent current	reat)	$I_{O} = 0$ to 150 mA, See Note 2	T _J = 25°C,		85	100	
(4)	(GND terminal cur	rent)	I _O = 0 to 150 mA,	See Note 2			140	μA
			EN < 0.5 V,	TJ = 25°C		0.5	1	·
	Standby current		EN < 0.5 V				2	
Vn	Output noise volta	ge	$\begin{array}{l} BW=300 \; Hz \; \mathrm{to} \; 50 \; kHz, \\ T_J=25^\circC, \end{array}$	C _O = 10 μF, See Note 2		50		μV
	Bypass voltage		TJ = 25°C			1.192		V
PSRR	Ripple rejection		$f = 1 \text{ kHz}, C_0 = 10 \mu\text{F},$	$T_J = 25^{\circ}C$, See Note 2		60		dB
	Current limit		T _J = 25°C	See Note 3		0.8	1.5	А

NOTES: 2. Minimum IN operating voltage is 2.7 V or $V_{O(typ)}$ + 1 V, whichever is greater. 3. Test condition includes, output voltage V_{O} =0 V and pulse duration = 10 mS.



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electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(typ)} + 1 V$, $I_O = 1 mA$, EN = IN, $C_o = 4.7 \mu F$ (unless otherwise noted) (continued)

	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
	Output voltage line regulation (2	vv0/v0)	$V_{O} + 1 V < V_{I} \le 10 V$,	$V_{I} \geq 3.5 \text{ V}, T_{J} = 25^{\circ}C$		0.04	0.07	%/V	
	(see Note 4)		V _O + 1 V < V _I ≤ 10 V,	$V_{I} \ge 3.5 V$			0.1	70/ V	
VIH	EN high level input		See Note 2			1.4	2	v	
VIL	EN low level input		See Note 2		0.5	1.2		v	
ı.	EN input current		EN = 0 V			-0.01	-0.5	- uA	
łı			EN = IN			-0.01	-0.5		
			I _O = 0 mA,	TJ = 25°C		0.2			
			I _O = 1 mA,	T _J = 25°C		3			
			I _O = 50 mA,	TJ = 25°C		120	150	mV	
			I _O = 50 mA				200		
		TPS76425	I _O = 75 mA,	T _J = 25°C		180	225		
			I _O = 75 mA				300		
			I _O = 100 mA,	TJ = 25°C		240	300		
			I _O = 100 mA				400		
			I _O = 150 mA,	TJ = 25°C		360	450		
Vno	Dropout voltage (see Note 5)		I _O = 150 mA				600		
VDO	Diopoul vollage (see Note 3)		I _O = 0 mA,	TJ = 25°C		0.2			
			I _O = 1 mA,	T _J = 25°C		3			
			I _O = 50 mA,	T _J = 25°C		100	125		
			I _O = 50 mA				166		
		TPS76433	I _O = 75 mA,	TJ = 25°C		150	188	mV	
		11 57 0455	I _O = 75 mA				250	IIIV	
			I _O = 100 mA,	TJ = 25°C		200	250		
			I _O = 100 mA				333		
			I _O = 150 mA,	TJ = 25°C		300	375		
			I _O = 150 mA				500		

NOTES: 2. Minimum IN operating voltage is 2.7 V or $V_{O(typ)}$ + 1 V, whichever is greater. 4. If $V_O < 2.5$ V and V_{Imax} = 10 V, V_{Imin} = 3.5 V:

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{Imax} - 3.5 V)}{100} \times 1000$$

If $V_{O} > 2.5$ V and $V_{Imax} = 10$ V, $V_{Imin} = V_{O} + 1$ V:

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{Imax} - (V_O + 1))}{100} \times 1000$$

5. Dropout voltage is defined as the differential voltage between VO and VI when VO drops 100 mV below the value measured with $V_{I} = V_{O} + 1.0 V.$

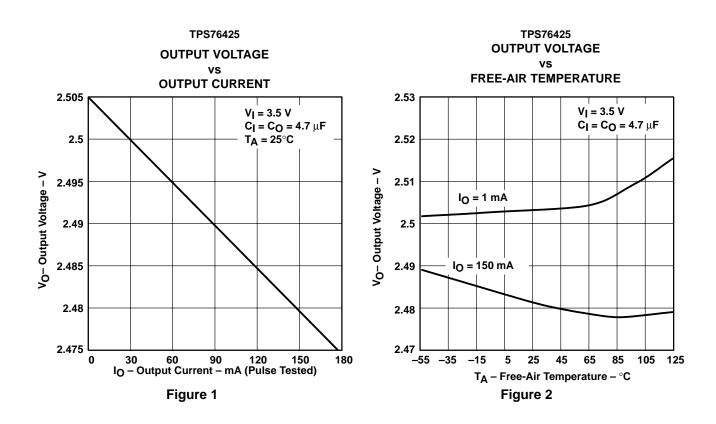


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TYPICAL CHARACTERISTICS

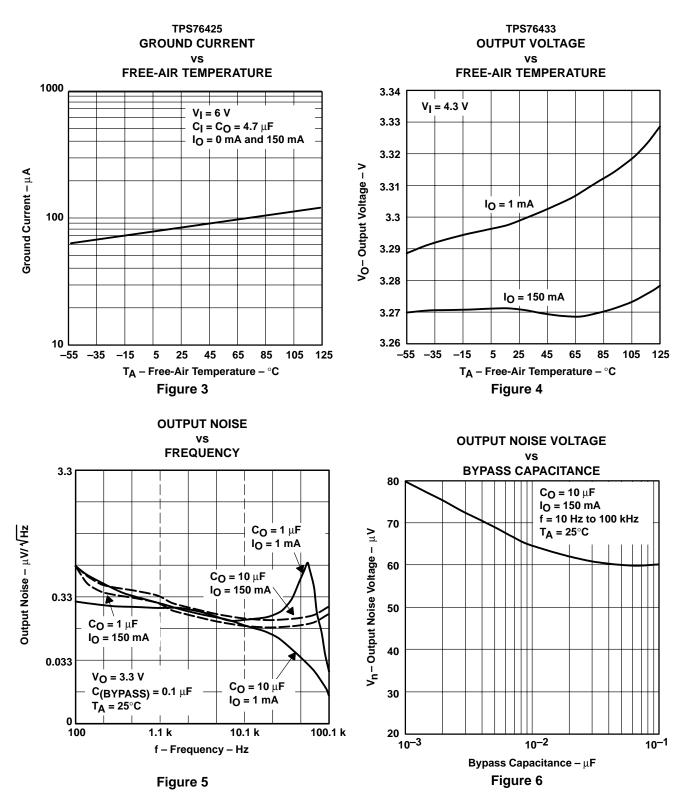
Table of Graphs

			FIGURE
Ma		vs Output current	1
VO	Output voltage	vs Free-air temperature	2, 3, 4
Vn	Output noise	vs Frequency	5
v _n		vs Bypass capacitance	6
	Output noise voltage	vs Load current	7
Z ₀	Output impedance	vs Frequency	8
VDO	Dropout voltage	vs Free-air temperature	9
	Ripple rejection	vs Frequency	10
	Line transient response		11, 13
	Load transient response		12, 14
	Companyation parios registeres (CSD)	vs Output current	15, 17
	Compensation series resistance (CSR)	vs Added ceramic capacitance	16, 18





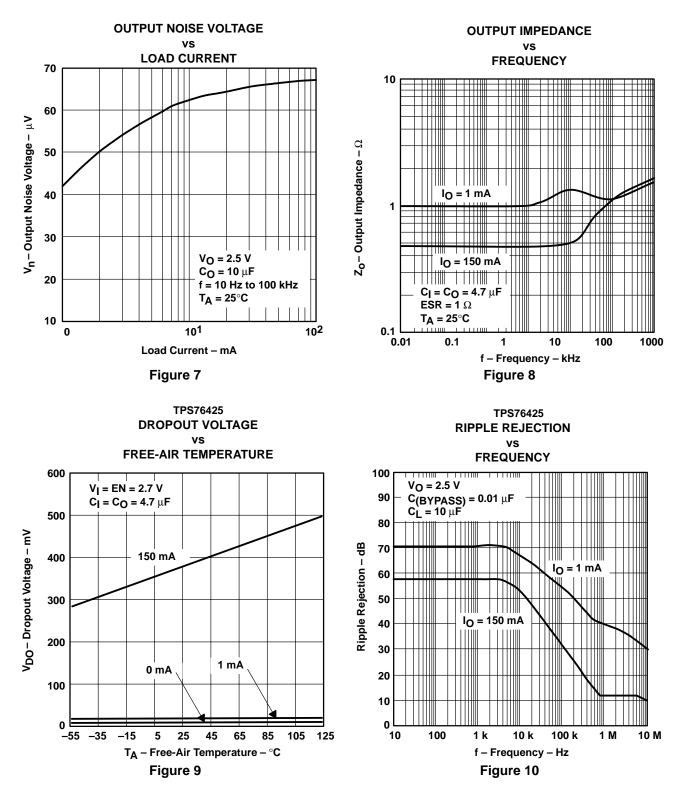
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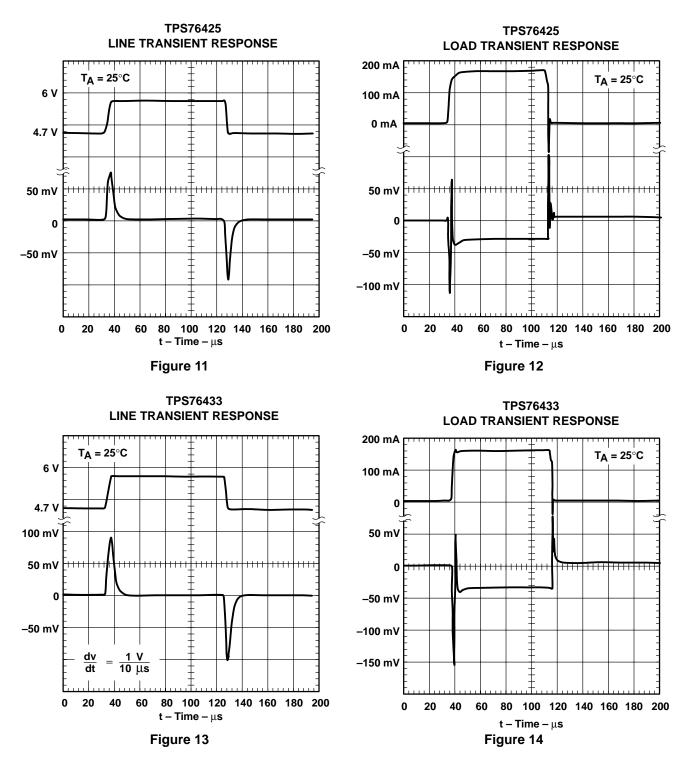
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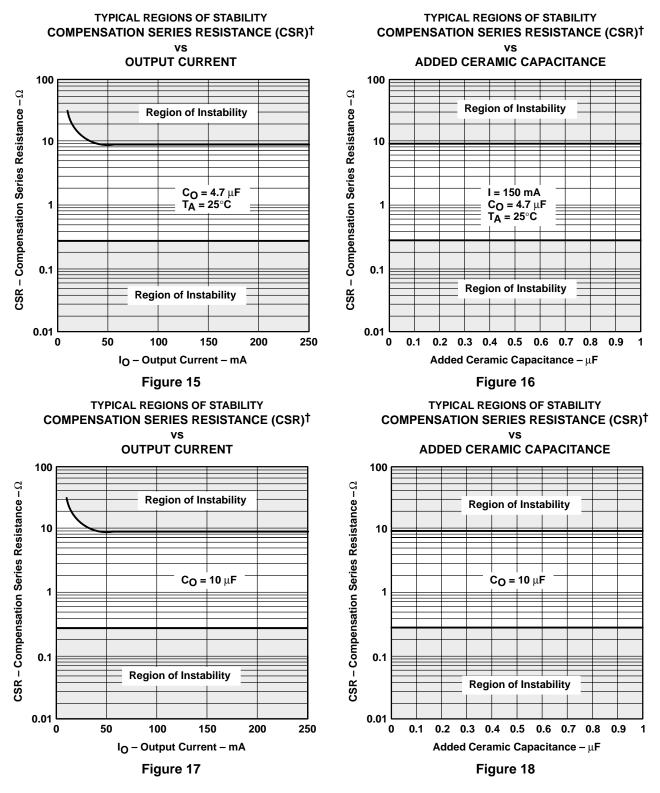
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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

[†] CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.



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APPLICATION INFORMATION

The TPS764xx family of low-noise and low-dropout (LDO) regulators are optimized for use in battery-operated equipment. They feature extremely low noise (50 μ V), low dropout voltages, low quiescent current (140 μ A), and an enable input to reduce supply current to less than 2 μ A when the regulator is turned off.

device operation

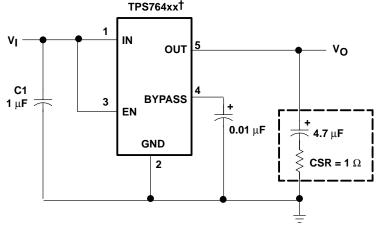
The TPS764xx uses a PMOS pass element to dramatically reduce both dropout voltage and supply current over more conventional PNP-pass-element LDO designs. The PMOS pass element is a voltage-controlled device which, unlike a PNP transistor, does not require increased drive current as output current increases. Supply current in the TPS764xx is essentially constant from no-load to maximum load.

Current limiting and thermal protection prevent damage by excessive output current and/or power dissipation. The device switches into a constant-current mode at approximately 1 A; further load reduces the output voltage instead of increasing the output current. The thermal protection shuts the regulator off if the junction temperature rises above 165°C. Recovery is automatic when the junction temperature drops approximately 25°C below the high temperature trip point. The PMOS pass element includes a back diode that safely conducts reverse current when the input voltage level drops below the output voltage level.

An internal resistor, in conjunction with external 0.01- μ F bypass capacitor, creates a low-pass filter to further reduce the noise. The TPS764xx exhibits only 50 μ V of output voltage noise using 0.01 μ F bypass and 4.7- μ F output capacitors.

A logic low on the enable input, EN, shuts off the output and reduces the supply current to less than 2 μ A. EN should be tied high in applications where the shutdown feature is not used.

A typical application circuit is shown in Figure 19.



[†] TPS76425, TPS76427 TPS76430, TPS76433.

Figure 19. Typical Application Circuit



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APPLICATION INFORMATION

external capacitor requirements

Although not required, a 0.047-µF or larger ceramic bypass input capacitor, connected between IN and GND and located close to the TPS764xx, is recommended to improve transient response and noise rejection. A higher-value electrolytic input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like all low dropout regulators, the TPS764xx requires an output capacitor connected between OUT and GND to stabilize the internal loop control. The minimum recommended capacitance value is 4.7 μ F and the ESR (equivalent series resistance) must be between 0.2 Ω and 10 Ω . Capacitor values 4.7 μ F or larger are acceptable, provided the ESR is less than 10 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7 μ F surface-mount solid tantalum capacitors, including devices from Sprague, Kemet, and Nichico, meet the ESR requirements previously stated. Multilayer ceramic capacitors should have minimum values of 1 μ F over the full operating temperature range of the equipment.

PART NO.	MFR.	VALUE	MAX ESR [†]	SIZE (H \times L \times W) [†]
T494B475K016AS	KEMET	4.7 μF	1.5 Ω	$1.9\times3.5\times2.8$
195D106x0016x2T	SPRAGUE	10 µF	1.5 Ω	$1.3\times7.0\times2.7$
695D106x003562T	SPRAGUE	10 µF	1.3 Ω	$2.5\times7.6\times2.5$
TPSC475K035R0600	AVX	4.7 μF	0.6 Ω	$2.6\times6.0\times3.2$

CAPACITOR SELECTION

[†] Size is in mm. ESR is maximum resistance in ohms at 100 kHz and $T_A = 25^{\circ}$ C. Listings are sorted by height.



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APPLICATION INFORMATION

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125°C; the maximum junction temperature allowable without damaging the device is 150°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_{D} , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$\mathsf{P}_{\mathsf{D}(\mathsf{max})} = \frac{\mathsf{T}_{\mathsf{J}}\mathsf{max} - \mathsf{T}_{\mathsf{A}}}{\mathsf{R}_{\theta}\mathsf{J}\mathsf{A}}$$

Where:

T_Jmax is the maximum allowable junction temperature

 $R_{\theta,JA}$ is the thermal resistance junction-to-ambient for the package, see the dissipation rating table.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$\mathsf{P}_{\mathsf{D}} = \left(\mathsf{V}_{\mathsf{I}} - \mathsf{V}_{\mathsf{O}}\right) \times \mathsf{I}_{\mathsf{O}}$$

Power dissipation resulting from quiescent current is negligible.

regulator protection

The TPS764xx pass element has a built-in back diode that safely conducts reverse current when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage is anticipated, external limiting might be appropriate.

The TPS764xx also features internal current limiting and thermal protection. During normal operation, the TPS764xx limits output current to approximately 800 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below 140°C, regulator operation resumes.

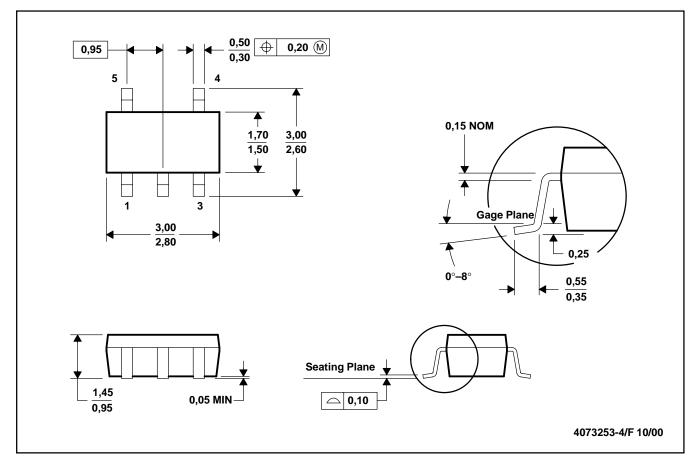


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MECHANICAL DATA

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178



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